

STPS61170C

High voltage power Schottky rectifier

Features

- High junction temperature capability
- Low leakage current
- Good trade off between leakage current and forward voltage drop
- Low thermal resistance
- High frequency operation
- Avalanche specification

Description

Dual center tab Schottky rectifier suited for high frequency switched mode power supply.

Packaged in TO-247, this device is intended for use to enhance the reliability of the application.

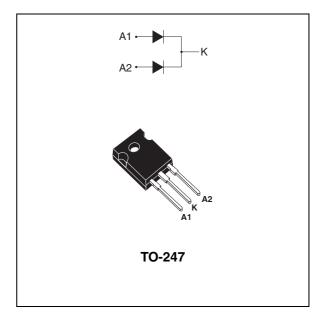


Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 30 A
V _{RRM}	170 V
Тj	175 °C
V _{F (max)}	0.67 V

Characteristics 1

Table 2.	Absolute ratings	(limiting values.	per diode)
	Absolute ratings	(minung values,	per aloac)

Symbol	Parameter					Unit
V _{RRM}	Repetitive peak reverse voltage				170	V
I _{F(RMS)}	Forward rms current				80	А
	Average forward current	rd current $T_{\rm C} = 150 \ ^{\circ}{\rm C} \ \delta = 0.5$ Per diode		30	А	
I _{F(AV)}	Average forward current	$1_{\rm C} = 150^{\circ} \rm C 0 =$	0.5	Per device	60	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			500	А	
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25 \ ^{\circ}C$			31800	W	
V _{ARM} ⁽¹⁾	Maximum repetitive peak avalanche voltage $t_p = 1 \ \mu s, T_j < 150 \ ^{\circ}C,$				200	V
V _{ASM} ⁽¹⁾	Maximum single pulse peak avalanche voltage $I_{AR}^{P} < 47 \text{ A}^{2}$				200	v
T _{stg}	Storage temperature range				-65 to + 175	°C
Тj	Maximum operating junction temperature ⁽²⁾				175	°C
dV/dt	Critical rate of rise reverse voltage				10000	V/µs

1. Refer to Figure 11

 $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink 2.

Table 3. Thermal resistance parameters

Symbol	Parameter	Value	Unit
R _{th (j-c)}	Junction to case Per diode Total	0.9 0.6	°C/W
R _{th (c)}	Coupling	0.3	

When the diodes 1 and 2 are used simultaneously : ΔT_{i} (diode 1) = P(diode1) x R_{th(i-c)}(Per diode) + P(diode 2) x R_{th(c)}

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Poverce leakage ourrent	T _j = 25 °C	V _ V			60	μA
'R`´	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	$V_{R} = V_{RRM}$		16	60	mA
	$T_i = 1$	T _j = 25 °C	- I _F = 30 A			0.84	
V _F ⁽²⁾		T _j = 125 °C			0.63	0.67	V
V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 60 A			0.92	v	
		T _j = 125 °C	F = 00 A		0.76	0.80	

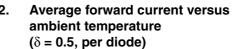
1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

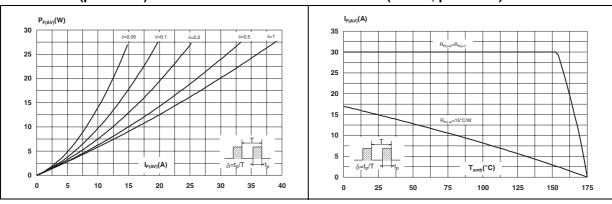
2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation : P = 0.54 x $I_{F(AV)}$ + 0.0043 ${I_F}^2_{(RMS)}$



Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)





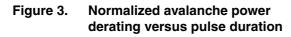


Figure 4. Normalized avalanche power derating versus junction temperature

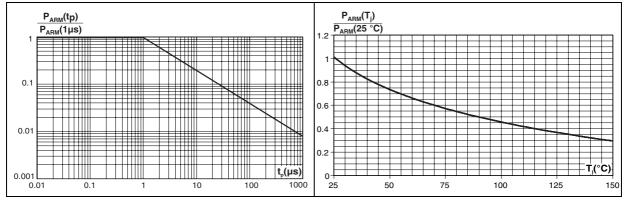
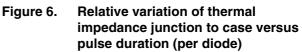
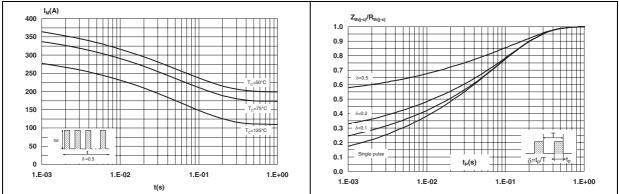
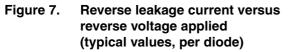
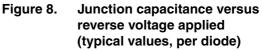


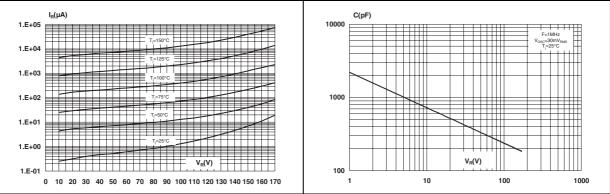
Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)











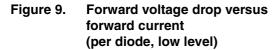


Figure 10. Forward voltage drop versus forward current (per diode, high level)

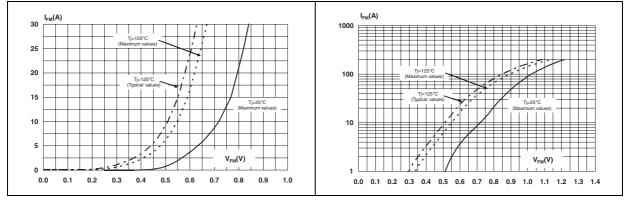
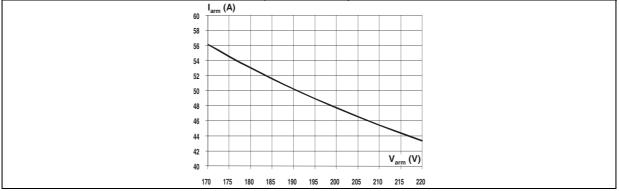


Figure 11. Reverse safe operating area($t_p < 1\mu s$ and $T_j < 150$ °C)





2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 to 1.0 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-247 dimensions

			Dimensions			
		Ref.	Millimeters		Inches	
			Min.	Max.	Min.	Max.
		А	4.85	5.15	0.191	0.203
		A1	2.20	2.60	0.086	0.102
		b	1.00	1.40	0.039	0.055
E	A Heat-sink plane	h1	2.00	2.40	0.078	0.094
S OR		b2	3.00	3.40	0.118	0.133
) c	0.40	0.80	0.015	0.031
		D ⁽¹⁾	19.85	20.15	0.781	0.793
		E	15.45	15.75	0.608	0.620
$L \rightarrow + \underbrace{b1}{b2}$		е	5.45	typ.	0.21	5 typ.
		, L	14.20	14.80	0.559	0.582
i ← → l	<u>·</u> → <u> </u>	L1	3.70	4.30	0.145	0.169
		L2	18.5	0 typ.	0.728	3 typ.
		ØP ⁽²⁾	3.55	3.65	0.139	0.143
		ØR	4.50	5.50	0.177	0.217
		S	5.50	typ.	0.216	6 typ.

1. Dimension D plus gate protrusion does not exceed 20.5 mm

2. Resin thickness around the mounting hole is not less than 0.9 mm



3 Ordering information

Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS61170CW	STPS61170CW	TO-247	4.40 g	30	Tube

4 Revision history

Table 7. Document revision history

Date	Revision	Changes	
16-Sep-2005	1	First issue.	
01-Dic-2010	2	Updated Table 2 and added Figure 11.	



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



Doc ID 11643 Rev 2